

General Description

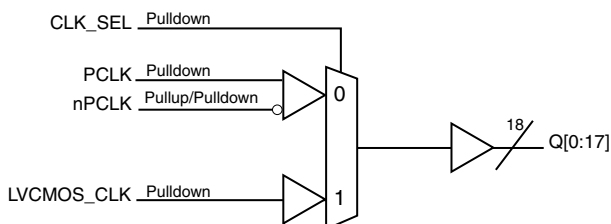
The ICS83940I-01 is a low skew, 1-to-18 LVPECL-to-LVCMOS/LVTTL Fanout Buffer. The ICS83940I-01 has two selectable clock inputs. The PCLK, nPCLK pair can accept LVPECL or SSTL input levels. The single-ended clock input accepts LVCMOS or LVTTL input levels.

The ICS83940I-01 is characterized at full 3.3V, full 2.5V and mixed 3.3V input and 2.5V output operating supply modes. Guaranteed output and part-to-part skew characteristics make the ICS83940I-01 ideal for those clock distribution applications demanding well defined performance and repeatability.

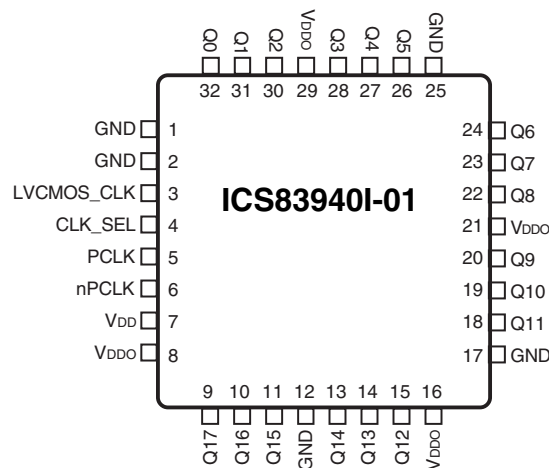
Features

- Eighteen LVCMOS/LVTTL outputs, 23Ω typical output impedance
- Selectable LVCMOS_CLK or LVPECL clock inputs
- PCLK, nPCLK pair can accept the following differential input levels: LVPECL, SSTL
- LVCMOS_CLK supports the following input types: LVCMOS or LVTTL
- Maximum output frequency: 175MHz
- Additive phase jitter, RMS: 0.108ps (typical), 3.3V/3.3V
- Output skew: 115ps (maximum)
- Part-to-part skew: 800ps (maximum), 3.3V/3.3V
- Operating supply modes:
 - Core/Output 3.3V/3.3V
 - 3.3V/2.5V
 - 2.5V/2.5V
- -40°C to 85°C ambient operating temperature
- Available in both standard (RoHS 5) and lead-free (RoHS 6) packages

Block Diagram



Pin Assignment



32-Lead LQFP
7mm x 7mm x 1.4mm package body
Y Package
Top View

Table 1. Pin Descriptions

Number	Name	Type		Description
1, 2, 12, 17, 25	GND	Power		Power supply ground.
3	LVCMOS_CLK	Input	Pulldown	Single-ended clock input. LVCMOS/LVTTL interface levels.
4	CLK_SEL	Input	Pulldown	Clock select input. When HIGH, selects LVCMOS_CLK input. When LOW, selects PCLK, nPCLK inputs. LVCMOS / LVTTL interface levels.
5	PCLK	Input	Pulldown	Non-inverting differential LVPECL clock input.
6	nPCLK	Input	Pullup/ Pulldown	Inverting differential LVPECL clock input. $V_{DD}/2$ default when left floating.
7	V_{DD}	Power		Power supply pin.
8, 16, 21, 29	V_{DDO}	Power		Output supply pins.
9, 10, 11, 13, 14, 15, 18, 19, 20, 22, 23, 24, 26, 27, 28, 30, 31, 32	Q17, Q16, Q15, Q14, Q13, Q12, Q11, Q10, Q9, Q8, Q7, Q6, Q5, Q4, Q3, Q2, Q1, Q0	Output		Single-ended clock outputs. LVCMOS/LVTTL interface levels.

NOTE: *Pullup and Pulldown* refers to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C_{IN}	Input Capacitance			4		pF
$R_{PULLDOWN}$	Input Pulldown Resistor			51		k Ω
R_{PULLUP}	Input Pullup Resistor			51		k Ω
C_{PD}	Power Dissipation Capacitance (per output)			9		pF
R_{OUT}	Output Impedance		17	23	28	Ω

Function Tables

Table 3A. Clock Select Function Table

Control Input	Clock	
CLK_SEL	PCLK, nPCLK	LVCMOS_CLK
0	Selected	De-selected
1	De-selected	Selected

Table 3B. Clock Input Function Table

Inputs				Outputs	Input to Output Mode	Polarity
CLK_SEL	LVCMOS_CLK	PCLK	nPCLK	Q[0:17]		
0	–	0	1	LOW	Differential to Single-Ended	Non-Inverting
0	–	1	0	HIGH	Differential to Single-Ended	Non-Inverting
0	–	0	Biased; NOTE 1	LOW	Single-Ended to Single-Ended	Non-Inverting
0	–	1	Biased; NOTE 1	HIGH	Single-Ended to Single-Ended	Non-Inverting
0	–	Biased; NOTE 1	0	HIGH	Single-Ended to Single-Ended	Inverting
0	–	Biased; NOTE 1	1	LOW	Single-Ended to Single-Ended	Inverting
1	0	–	–	LOW	Single-Ended to Single-Ended	Non-Inverting
1	1	–	–	HIGH	Single-Ended to Single-Ended	Non-Inverting

NOTE 1: Please refer to the Application Information Section, *Wiring the Differential Input to Accept Single-ended Levels*.

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{DD}	3.6V
Inputs, V_I	-0.3V to $V_{DD} + 0.3V$
Outputs, V_O	-0.3V to $V_{DDO} + 0.3V$
Input Current, I_{IN}	$\pm 20\text{mA}$
Package Thermal Impedance, θ_{JA}	53.5°C/W (0 mps)
Storage Temperature, T_{STG}	-40°C to 125°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Power Supply Current				26	mA
I_{DDO}	Output Supply Current	No Load			28	mA

Table 4B. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		2.375	2.5	2.625	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				25	mA
I_{DDO}	Output Supply Current	No Load			26	mA

Table 4C. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				26	mA
I_{DDO}	Output Supply Current	No Load			26	mA

Table 4D. LVCMOS DC Characteristics, $V_{DD} = 3.3V \pm 5\%$ or $2.5V \pm 5\%$, $V_{DDO} = 3.3V \pm 5\%$ or $2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage	LVCMOS_CLK	$V_{DD} = 3.3V$ or $2.5V$		$V_{DD} + 0.3$	V
		CLK_SEL				
V_{IL}	Input Low Voltage	LVCMOS_CLK	$V_{DD} = 3.3V$ or $2.5V$	-0.3	1.3	V
		CLK_SEL	$V_{DD} = 3.3V$ or $2.5V$	-0.3	0.8	V
I_{IH}	Input High Current	CLK_SEL, LVCMOS_CLK	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$		150	μA
I_{IL}	Input Low Current	CLK_SEL, LVCMOS_CLK	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$		-5	μA
V_{OH}	Output High Voltage; NOTE 1		$V_{DDO} = 3.465V$	2.8		V
			$V_{DDO} = 2.625V$	2.1		V
V_{OL}	Output Low Voltage; NOTE 1		$V_{DDO} = 3.465V$ or $2.65V$		0.55	V

NOTE 1: Outputs terminated with 50Ω to $V_{DDO}/2$. See Parameter Measurement Information section, *Output Load Test Circuit diagram*.

Table 4E. LVPECL DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
I_{IH}	Input High Current	PCLK, nPCLK	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$		150	μA
I_{IL}	Input Low Current	PCLK	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$		-10	μA
		nPCLK	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$		-150	μA
I_{IN}	Input Current				± 200	μA
V_{PP}	Peak-to-Peak Input Voltage		500		1000	mV
V_{CMR}	Common Mode Input Voltage; NOTE 1		$V_{DD} - 1.4$		$V_{DD} - 0.6$	V

NOTE 1: Common mode voltage is defined as V_{IH} .

Table 4F. LVPECL DC Characteristics, $V_{DD} = 3.3V \pm 5\%$ or $2.5V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
I_{IH}	Input High Current	PCLK, nPCLK	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$		150	μA
I_{IL}	Input Low Current	PCLK	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$		-10	μA
		nPCLK	$V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$		-150	μA
I_{IN}	Input Current				± 200	μA
V_{PP}	Peak-to-Peak Input Voltage		300		1000	mV
V_{CMR}	Common Mode Input Voltage; NOTE 1		$V_{DD} - 1.4$		$V_{DD} - 0.6$	V

NOTE 1: Common mode voltage is defined as V_{IH} .

AC Electrical Characteristics

Table 5A. AC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency					175	MHz
t_{PLH}	Propagation Delay	PCLK, nPCLK; NOTE 1, 5	$f \leq 150MHz$	1.6		3.0	ns
		LVCMOS_CLK; NOTE 2, 5	$f \leq 150MHz$	1.8		3.0	ns
	Propagation Delay	PCLK, nPCLK; NOTE 1, 5	$f > 150MHz$	1.6		3.3	ns
		LVCMOS_CLK; NOTE 2, 5	$f > 150MHz$	1.8		3.2	ns
f_{jit}	Additive Phase Jitter, RMS; Refer to Additive Phase Jitter Section	PCLK, nPCLK	155.52MHz, Integration Range: 12kHz – 20MHz		0.145		ps
		LVCMOS_CLK			0.108		ps
$t_{sk(o)}$	Output Skew; NOTE 3, 5		Measured on the Rising Edge @ $V_{DDO}/2$			115	ps
$t_{sk(pp)}$	Part-to-Part Skew; NOTE 6	PCLK, nPCLK	$f \leq 150MHz$			1.4	ns
		LVCMOS_CLK	$f \leq 150MHz$			1.2	ns
	Part-to-Part Skew; NOTE 6	PCLK/nPCLK	$f > 150MHz$			1.7	ns
		LVCMOS_CLK	$f > 150MHz$			1.4	ns
	Part-to-Part Skew; NOTE 4, 5	PCLK/nPCLK	Measured on the Rising Edge @ $V_{DDO}/2$			975	ps
		LVCMOS_CLK				800	ps
t_R / t_F	Output Rise/Fall Time		20% to 80%	300		800	ps
odc	Output Duty Cycle		$f \leq 150MHz$	45		55	%

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE: All parameters measured at 150MHz unless noted otherwise.

NOTE 1: Measured from the differential input crossing point to the output $V_{DDO}/2$.

NOTE 2: Measured from $V_{DD}/2$ to $V_{DDO}/2$.

NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DDO}/2$.

NOTE 4: Defined as skew between outputs on different devices operating at the same supply voltage, same temperature, same frequency and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDO}/2$.

NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 6: Defined as skew between outputs on different devices, across temperature and voltage ranges, same frequency and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDO}/2$.

Table 5B. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units	
f_{OUT}	Output Frequency				175	MHz	
t_{PLH}	Propagation Delay	PCLK, nPCLK; NOTE 1, 5	$f \leq 150MHz$	1.7	3.2	ns	
		LVCOSMOS_CLK; NOTE 2, 5	$f \leq 150MHz$	1.7	3.0	ns	
	Propagation Delay	PCLK, nPCLK; NOTE 1, 5	$f > 150MHz$	1.6	3.4	ns	
		LVCOSMOS_CLK; NOTE 2, 5	$f > 150MHz$	1.8	3.3	ns	
f_{jit}	Additive Phase Jitter, RMS; Refer to Additive Phase Jitter Section	PCLK, nPCLK	155.52MHz, Integration Range: 12kHz – 20MHz	0.199		ps	
		LVCOSMOS_CLK		0.137		ps	
$t_{sk(o)}$	Output Skew; NOTE 3, 5	Measured on the Rising Edge @ $V_{DDO}/2$			150	ps	
$t_{sk(pp)}$	Part-to-Part Skew; NOTE 6	PCLK, nPCLK	$f \leq 150MHz$		1.5	ns	
		LVCOSMOS_CLK	$f \leq 150MHz$		1.3	ns	
	Part-to-Part Skew; NOTE 6	PCLK, nPCLK	$f > 150MHz$		1.8	ns	
		LVCOSMOS_CLK	$f > 150MHz$		1.5	ns	
	Part-to-Part Skew; NOTE 4, 5	PCLK, nPCLK	Measured on the Rising Edge @ $V_{DDO}/2$			975	ps
		LVCOSMOS_CLK				875	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	300		800	ps	
odc	Output Duty Cycle	$f \leq 150MHz$	45		55	%	

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE: All parameters measured at 150MHz unless noted otherwise.

NOTE 1: Measured from the differential input crossing point to the output $V_{DDO}/2$.

NOTE 2: Measured from $V_{DD}/2$ to $V_{DDO}/2$.

NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DDO}/2$.

NOTE 4: Defined as skew between outputs on different devices operating at the same supply voltage, same temperature, same frequency and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDO}/2$.

NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 6: Defined as skew between outputs on different devices, across temperature and voltage ranges, same frequency and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDO}/2$.

Table 5C. AC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units	
f_{OUT}	Output Frequency				175	MHz	
t_{PLH}	Propagation Delay	PCLK, nPCLK; NOTE 1, 5	$f \leq 150MHz$	1.2	3.8	ns	
		LVCOSMOS_CLK; NOTE 2, 5	$f \leq 150MHz$	1.5	3.2	ns	
	Propagation Delay	PCLK, nPCLK; NOTE 1, 5	$f > 150MHz$	1.5	3.7	ns	
		LVCOSMOS_CLK; NOTE 2, 5	$f > 150MHz$	2.0	3.6	ns	
f_{jit}	Additive Phase Jitter, RMS; Refer to Additive Phase Jitter Section	PCLK, nPCLK	155.52MHz, Integration Range: 12kHz – 20MHz	0.323		ps	
		LVCOSMOS_CLK		0.116		ps	
$t_{sk(o)}$	Output Skew; NOTE 3, 5	Measured on the Rising Edge @ $V_{DDO}/2$			150	ps	
$t_{sk(pp)}$	Part-to-Part Skew; NOTE 6	PCLK, nPCLK	$f \leq 150MHz$		2.6	ns	
		LVCOSMOS_CLK	$f \leq 150MHz$		1.7	ns	
	Part-to-Part Skew; NOTE 6	PCLK, nPCLK	$f > 150MHz$		2.2	ns	
		LVCOSMOS_CLK	$f > 150MHz$		1.7	ns	
	Part-to-Part Skew; NOTE 4, 5	PCLK, nPCLK	Measured on the Rising Edge @ $V_{DDO}/2$			1.2	ns
		LVCOSMOS_CLK				1	ns
t_R / t_F	Output Rise/Fall Time	20% to 80%	300		800	ps	
odc	Output Duty Cycle	$f \leq 150MHz$	43		57	%	

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE: All parameters measured at 150MHz unless noted otherwise.

NOTE 1: Measured from the differential input crossing point to the output $V_{DDO}/2$.

NOTE 2: Measured from $V_{DD}/2$ to $V_{DDO}/2$.

NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DDO}/2$.

NOTE 4: Defined as skew between outputs on different devices operating at the same supply voltage, same temperature, same frequency and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDO}/2$.

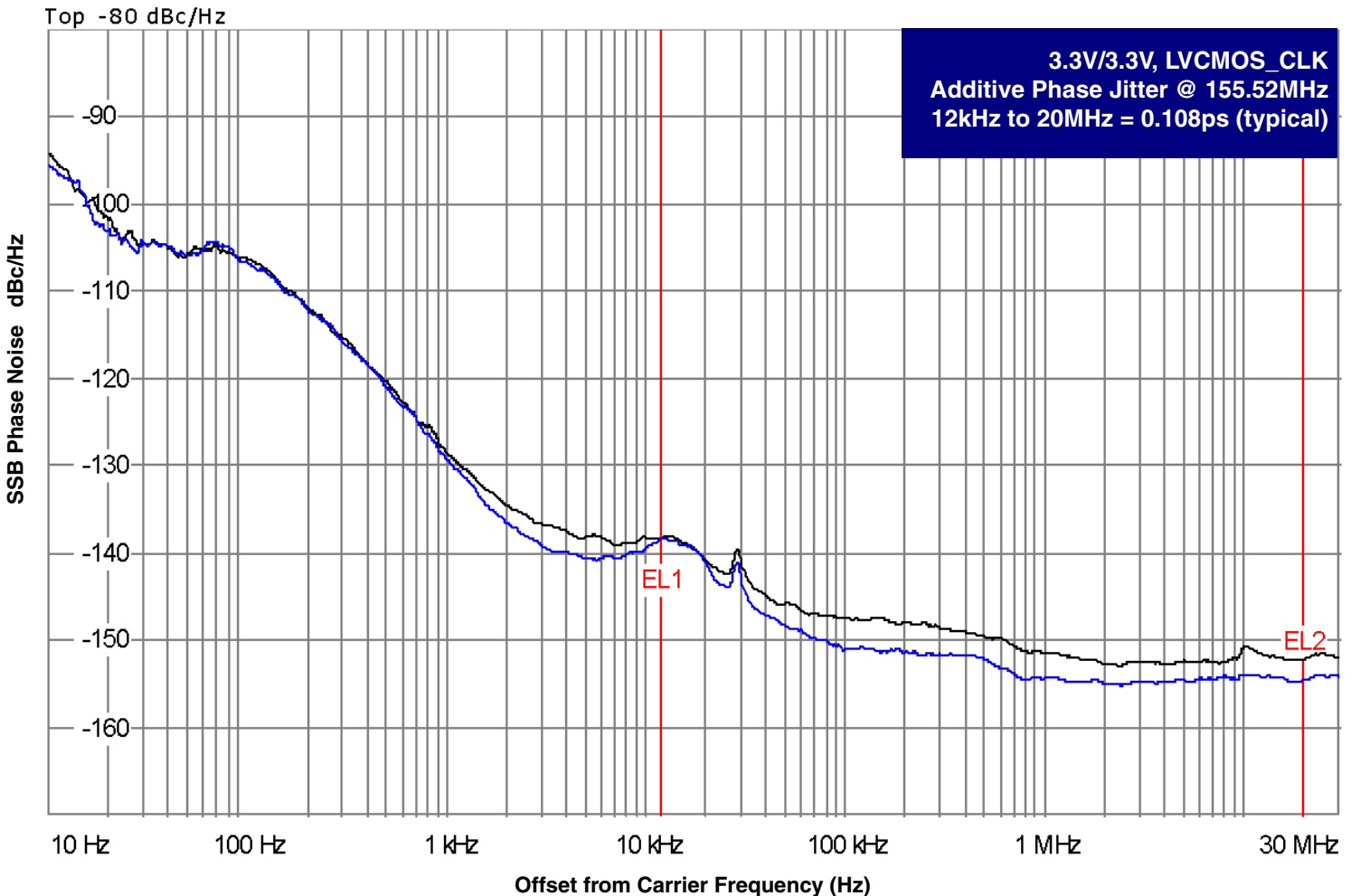
NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 6: Defined as skew between outputs on different devices, across temperature and voltage ranges, same frequency and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDO}/2$.

Additive Phase Jitter

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the **dBc Phase Noise**. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm) or a ratio

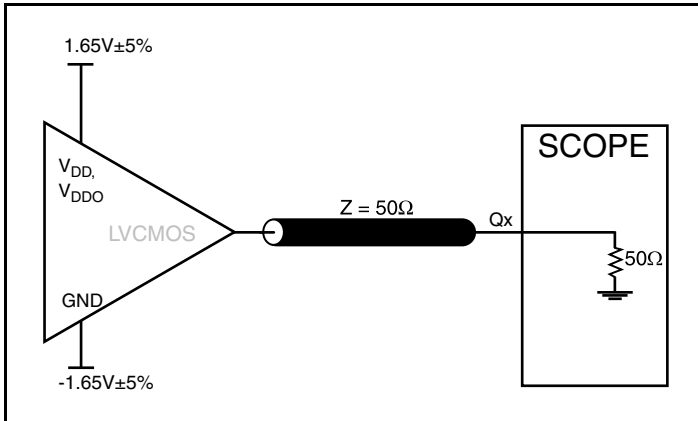
of the power in the 1Hz band to the power in the fundamental. When the required offset is specified, the phase noise is called a **dBc** value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.



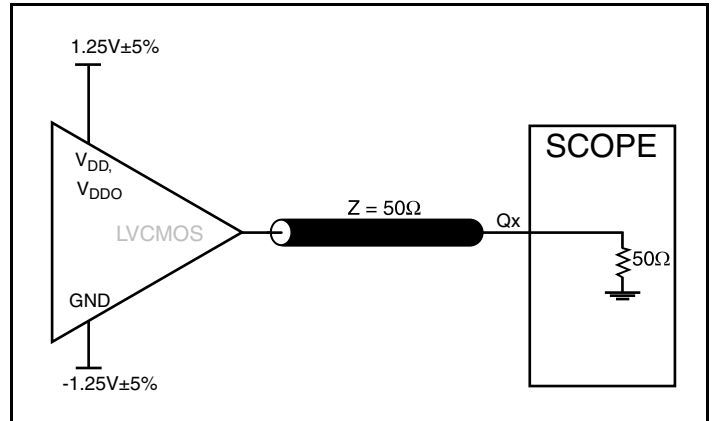
As with most timing specifications, phase noise measurements has issues relating to the limitations of the equipment. Often the noise floor of the equipment is higher than the noise floor of the device. This is illustrated above. The device meets the noise floor of what is shown, but can actually be lower. The phase noise is dependent on the input source and measurement equipment.

The source generator, "SMA 100A 9kHz – 6GHz Low Noise Signal Generator" as external input to an Agilent 8133A 3GHz Pulse Generator".

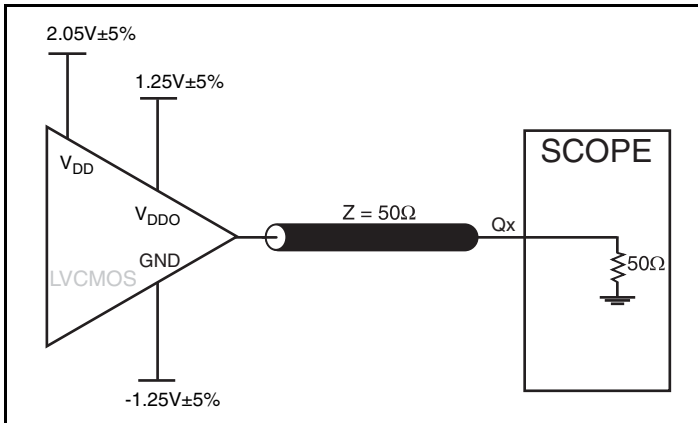
Parameter Measurement Information



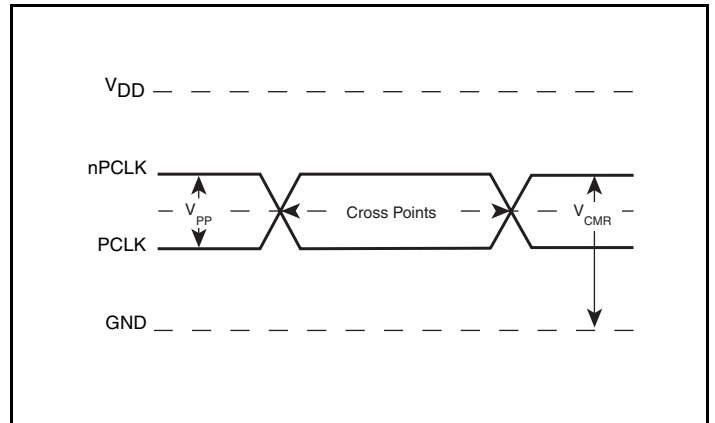
3.3V Core/3.3V LVCMOS Output Load AC Test Circuit



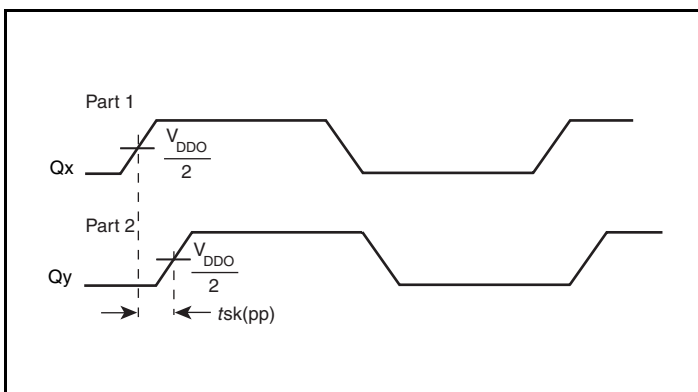
2.5V Core/2.5V LVCMOS Output Load AC Test Circuit



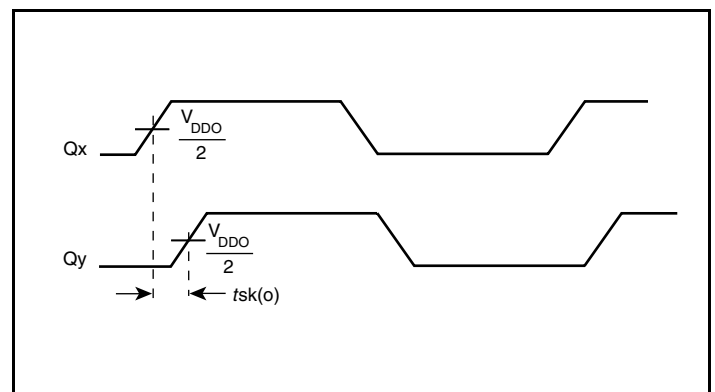
3.3V Core/2.5V LVCMOS Output Load AC Test Circuit



Differential Input Level

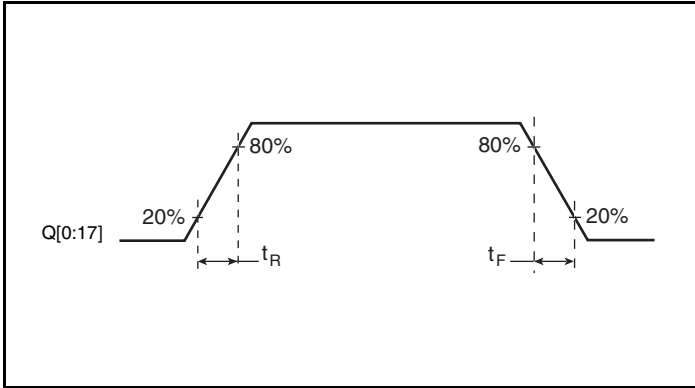


Part-to-Part Skew

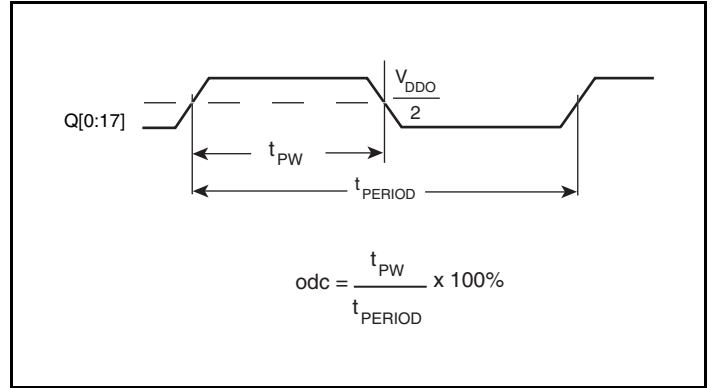


Output Skew

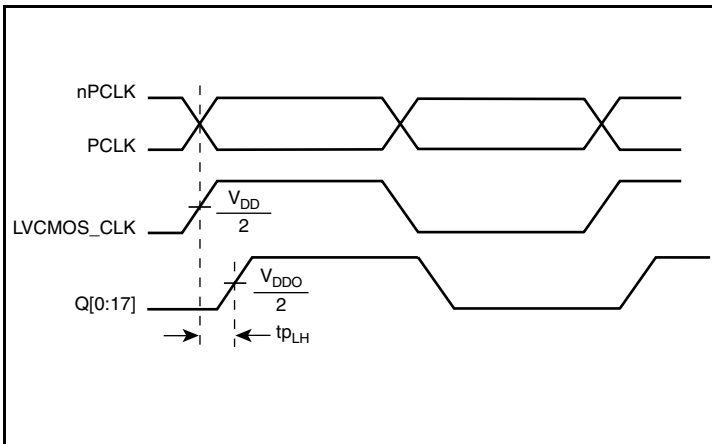
Parameter Measurement Information, continued



Output Rise/Fall Time



Output Duty Cycle/Pulse Width/Period



Propagation Delay

Applications Information

Wiring the Differential Input to Accept Single-Ended Levels

Figure 1 shows how a differential input can be wired to accept single ended levels. The reference voltage $V_{REF} = V_{CC}/2$ is generated by the bias resistors R1 and R2. The bypass capacitor (C1) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of R1 and R2 might need to be adjusted to position the V_{REF} in the center of the input voltage swing. For example, if the input clock swing is 2.5V and $V_{CC} = 3.3V$, R1 and R2 value should be adjusted to set V_{REF} at 1.25V. The values below are for when both the single ended swing and V_{CC} are at the same voltage. This configuration requires that the sum of the output impedance of the driver (R_o) and the series resistance (R_s) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R3 and R4 in parallel should equal the transmission

line impedance. For most 50Ω applications, R3 and R4 can be 100Ω. The values of the resistors can be increased to reduce the loading for slower and weaker LVCMOS driver. When using single-ended signaling, the noise rejection benefits of differential signaling are reduced. Even though the differential input can handle full rail LVCMOS signaling, it is recommended that the amplitude be reduced. The datasheet specifies a lower differential amplitude, however this only applies to differential signals. For single-ended applications, the swing can be larger, however V_{IL} cannot be less than -0.3V and V_{IH} cannot be more than $V_{CC} + 0.3V$. Though some of the recommended components might not be used, the pads should be placed in the layout. They can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a differential signal.

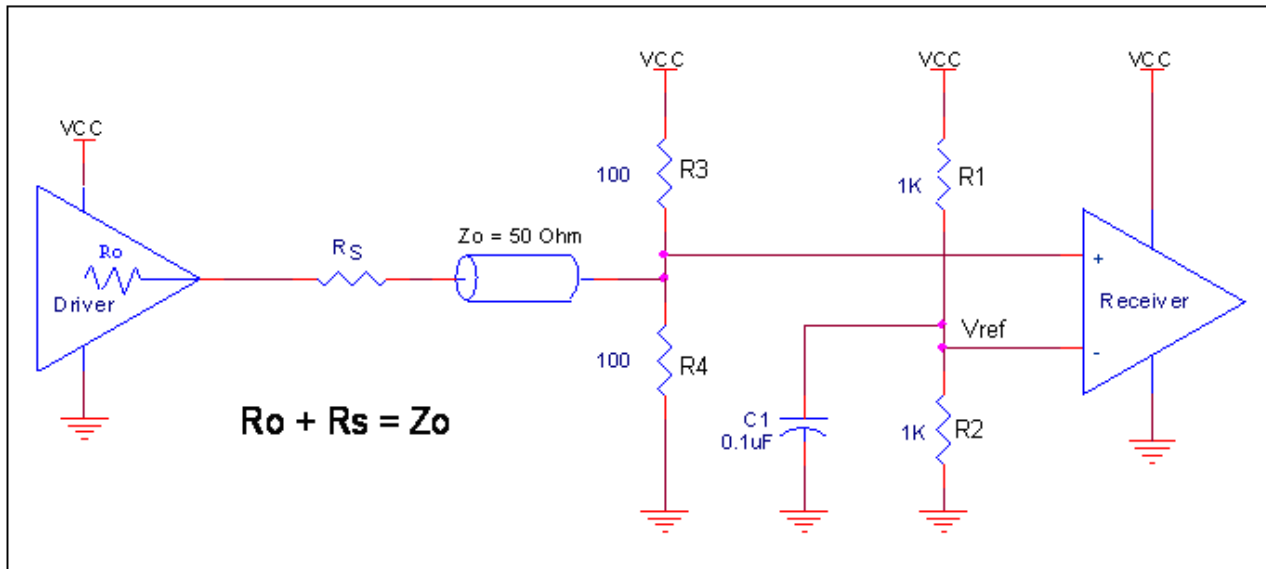


Figure 1. Recommended Schematic for Wiring a Differential Input to Accept Single-ended Levels

LVPECL Clock Input Interface

The PCLK/nPCLK accepts LVPECL, SSTL and other differential signals. Both differential signals must meet the V_{PP} and V_{CMR} input requirements. *Figures 2A to 2C* show interface examples for the PCLK/nPCLK input driven by the most common driver types. The

input interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.

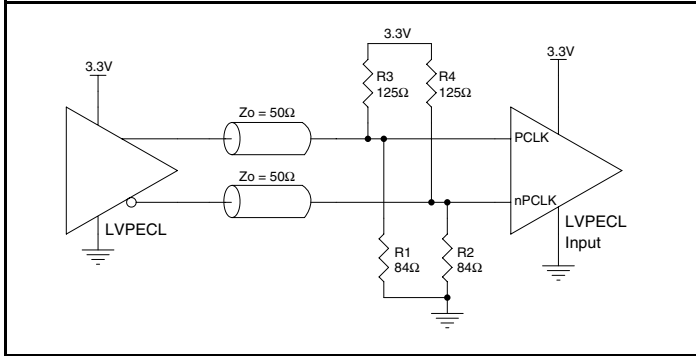


Figure 2A. PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver

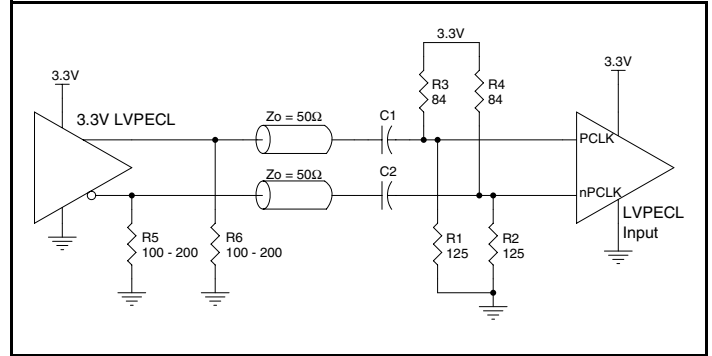


Figure 2B. PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver with AC Couple

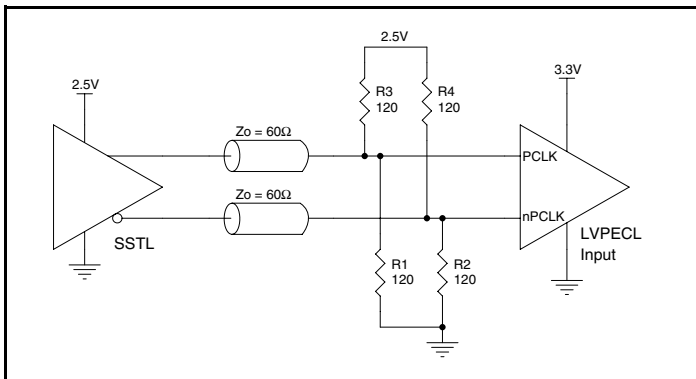


Figure 2C. PCLK/nPCLK Input Driven by an SSTL Driver

Recommendations for Unused Input and Output Pins

Inputs:

PCLK/nPCLK Inputs

For applications not requiring the use of the differential input, both PCLK and nPCLK can be left floating. Though not required, but for additional protection, a $1\text{k}\Omega$ resistor can be tied from PCLK to ground.

LVCMOS_CLK Input

For applications not requiring the use of a clock input, it can be left floating. Though not required, but for additional protection, a $1\text{k}\Omega$ resistor can be tied from the LVCMOS_CLK input to ground.

LVCMOS Control Pins

All control pins have internal pulldowns; additional resistance is not required but can be added for additional protection. A $1\text{k}\Omega$ resistor can be used.

Outputs:

LVCMOS Outputs

All unused LVCMOS output can be left floating. There should be no trace attached.

Power Considerations

This section provides information on power dissipation and junction temperature for the ICS83940DI-01. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS83940DI-01 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{DD} = 3.3V + 5\% = 3.465V$, which gives worst case results.

- Power (core)_{MAX} = $V_{DD_MAX} * (I_{DD} + I_{DDO}) = 3.465V * (26mA + 28mA) = \mathbf{187.11mW}$

Dynamic Power Dissipation at 175MHz

$$\text{Power (175MHz)} = C_{PD} * \text{Frequency} * (V_{DD})^2 * \text{number of outputs} = 9pF * 175MHz * (3.465V)^2 * 18 = \mathbf{340.4mW}$$

Total Power Dissipation

- Total Power**
= Power (core)_{MAX} + Power (175MHz)
= 187.15mW + 340.4mW
= **527.5mW**

2. Junction Temperature.

Junction temperature, T_j , is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature, T_j , to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for T_j is as follows: $T_j = \theta_{JA} * Pd_{total} + T_A$

T_j = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_{total} = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 53.5°C/W per Table 6 below.

Therefore, T_j for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ\text{C} + 0.528\text{W} * 53.5^\circ\text{C/W} = 113.2^\circ\text{C}. \text{ This is well below the limit of } 125^\circ\text{C}.$$

This calculation is only an example. T_j will vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 6. Thermal Resistance θ_{JA} for 32 Lead LQFP, Forced Convection

θ_{JA} by Velocity			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	53.5°C/W	48.0°C/W	44.0°C/W

Reliability Information

Table 7. θ_{JA} vs. Air Flow Table for a 32 Lead LQFP

θ_{JA} vs. Air Flow			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	53.5°C/W	48.0°C/W	44.0°C/W

Transistor Count

The transistor count for ICS83940I-01 is: 819

Package Outline and Package Dimensions

Package Outline - Y Suffix for 32 Lead LQFP

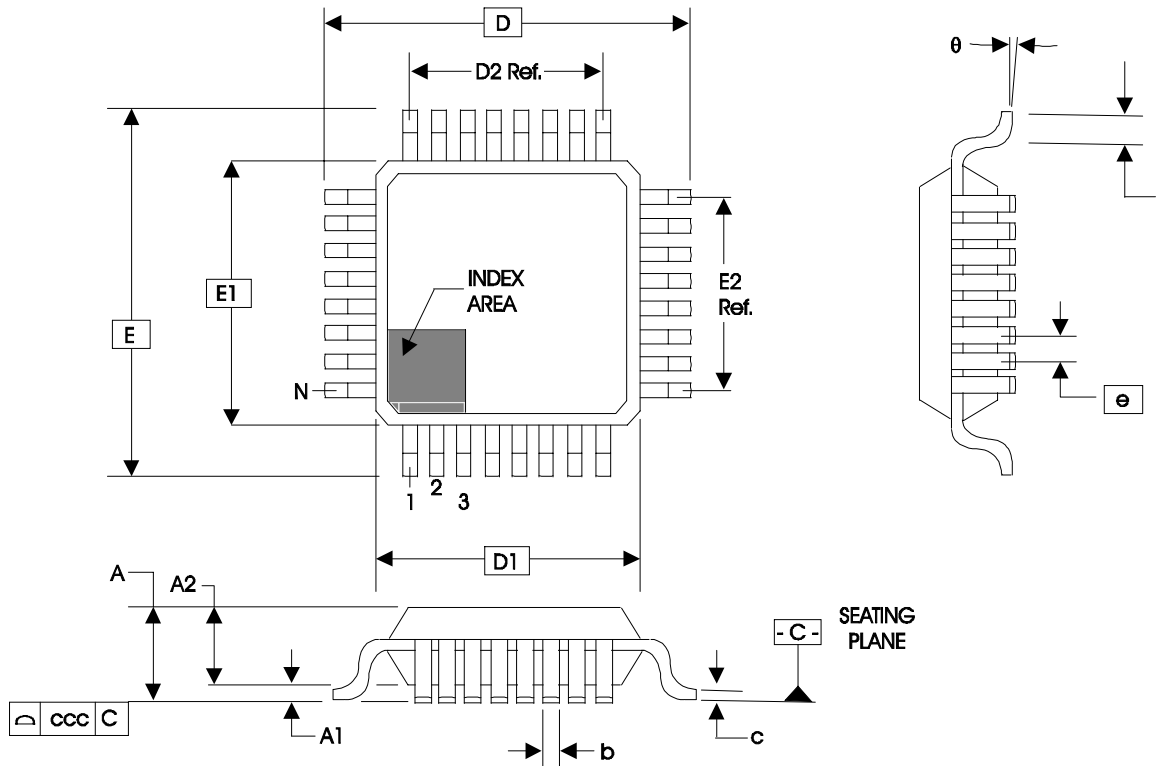


Table 8. Package Dimensions for 32 Lead LQFP

JEDEC Variation: ABC - HD			
All Dimensions in Millimeters			
Symbol	Minimum	Nominal	Maximum
N	32		
A			1.60
A1	0.05	0.10	0.15
A2	1.35	1.40	1.45
b	0.30	0.37	0.45
c	0.09		0.20
D & E	9.00 Basic		
D1 & E1	7.00 Basic		
D2 & E2	5.60 Ref.		
e	0.80 Basic		
L	0.45	0.60	0.75
θ	0°		7°
ccc			0.10

Reference Document: JEDEC Publication 95, MS-026

Ordering Information

Table 9. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
83940DYI-01	ICS83940DI01	32 Lead LQFP	Tray	-40°C to 85°C
83940DYI-01T	ICS83940DI01	32 Lead LQFP	1000 Tape & Reel	-40°C to 85°C
83940DYI-01LF	ICS83940DI01L	"Lead-Free" 32 Lead LQFP	Tray	-40°C to 85°C
83940DYI-01LFT	ICS83940DI01L	"Lead-Free" 32 Lead LQFP	1000 Tape & Reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

While the information presented herein has been checked for both accuracy and reliability, Integrated Device Technology (IDT) assumes no responsibility for either its use or for the infringement of any patents or other rights of third parties, which would result from its use. No other circuits, patents, or licenses are implied. This product is intended for use in normal commercial and industrial applications. Any other applications, such as those requiring high reliability or other extraordinary environmental requirements are not recommended without additional processing by IDT. IDT reserves the right to change any circuitry or specifications without notice. IDT does not authorize or warrant any IDT product for use in life support devices or critical medical instruments.

We've Got Your Timing Solution



6024 Silver Creek Valley Road
San Jose, California 95138

Sales

800-345-7015 (inside USA)
+408-284-8200 (outside USA)
Fax: 408-284-2775
www.IDT.com/go/contactIDT

Technical Support

netcom@idt.com
+480-763-2056

DISCLAIMER Integrated Device Technology, Inc. (IDT) and its subsidiaries reserve the right to modify the products and/or specifications described herein at any time and at IDT's sole discretion. All information in this document, including descriptions of product features and performance, is subject to change without notice. Performance specifications and the operating parameters of the described products are determined in the independent state and are not guaranteed to perform the same way when installed in customer products. The information contained herein is provided without representation or warranty of any kind, whether express or implied, including, but not limited to, the suitability of IDT's products for any particular purpose, an implied warranty of merchantability, or non-infringement of the intellectual property rights of others. This document is presented only as a guide and does not convey any license under intellectual property rights of IDT or any third parties.

IDT's products are not intended for use in life support systems or similar devices where the failure or malfunction of an IDT product can be reasonably expected to significantly affect the health or safety of users. Anyone using an IDT product in such a manner does so at their own risk, absent an express, written agreement by IDT.

Integrated Device Technology, IDT and the IDT logo are registered trademarks of IDT. Other trademarks and service marks used herein, including protected names, logos and designs, are the property of IDT or their respective third party owners.

Copyright 2010. All rights reserved.